

JAN2N6798 Information

Heisener.com

Part Number JAN2N6798

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH TO-205AF TO-39

Package TO-205AF Metal Can

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com





Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N6798	Specifica	tions
JANZN0/90	Specifica	uons

Manufacturer Part Number	JAN2N6798
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-205AF Metal Can
Series	Military, MIL-PRF-19500/557
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	5.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	42.07nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	800mW (Ta), 25W (Tc)
Rds On (Max) @ Id, Vgs	420 mOhm @ 5.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-39
Package / Case	TO-205AF Metal Can
	Report errors?

JAN2N6798 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N6798 Payment Methods



















JAN2N6798 Shipping Methods













If you have any question about JAN2N6798, please do not hesitate to contact us!

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